

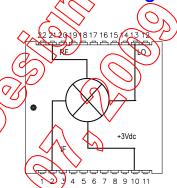
Product Features

- +35 dBm IIP3
- No external matching element Required
- RF 40 1000 MHz
- LO 30 900 MHz
- IF 5 250 MHz
- +17 dBm LO Drive Level
- +3V at 35mA DC Power Supply
- Low Cost Surface Mount J-Lead Package

Product Description

The HMJ5 is a high dynamic range GaAs FET mixer. This active FET mixer realizes a typical third order intercept point of +35 dBm at an LO drive level of +17 dBm. The HMJ5 comes in a low cost, J-Lead package. Typical applications include frequency up/down conversion, modulation and demodulation for receivers and transmitters used in communications systems.

Functional Diagram



Function	Pin No.
IF	2
LO	13
RF	21
+3V	10
Ground	All other pins

Specifications (1)

				$\sim \sim \sim$		
Parameter	Units	Min _	Tyr	M(V)	Condition	
RF Frequency Range	MHz	/4 0	(-P066)	2005		
LO Frequency Range	MHz	30	2-900	(90)		
IF Frequency Range	MHz	3	250			
SSB Conversion Loss	dB	79	7.5 9.0))		
Noise Figure	dB		9.5	1		
LO-RF Isolation	dB	(282)	28			
LO-IF Isolation	dB	1 24	30			
Input IP3	dBm 🗸) i	\$5	RF = 900 MHz @	0 dBm	
RF Return Loss	dB		1(.70)			
LO Return Loss	dB.	Y /	(8.8)			
IF Return Loss	dB		103			
Input P1dB	(dBin	\cup	+23			
LO Drive Level	dBm		+17			
DC Current at +3V Bias	$(1)_{mA}$	\bigcirc	35 60			
-	\sim	' (∀%) ' '				

Notes

- 1. Test conditions unless otherwise moted: 25 °C, RF = 905 MHz © 10 Bm, LO = 900MHz @ +17 dBm, IF = 5 MHz.

 2. Measured in a 50-Ohnr system with regimnal LO drive in a downconverter application only, unless otherwise specified.
- 3. LO frequency must be separated from IF frequency by a minimum of 2 MHz (i.e., $|F_{LO}|F_{IF}| \ge 2$ MHz).

Absolute Maximum Rating

Parameters	Rating
Operating Case Temperature	-40 to +85 °C
Storage Temperature	-65 to +100 °C
Device Voltage	+7 V
Device Current	69 mA
Maximum Input Power	+25 dBm

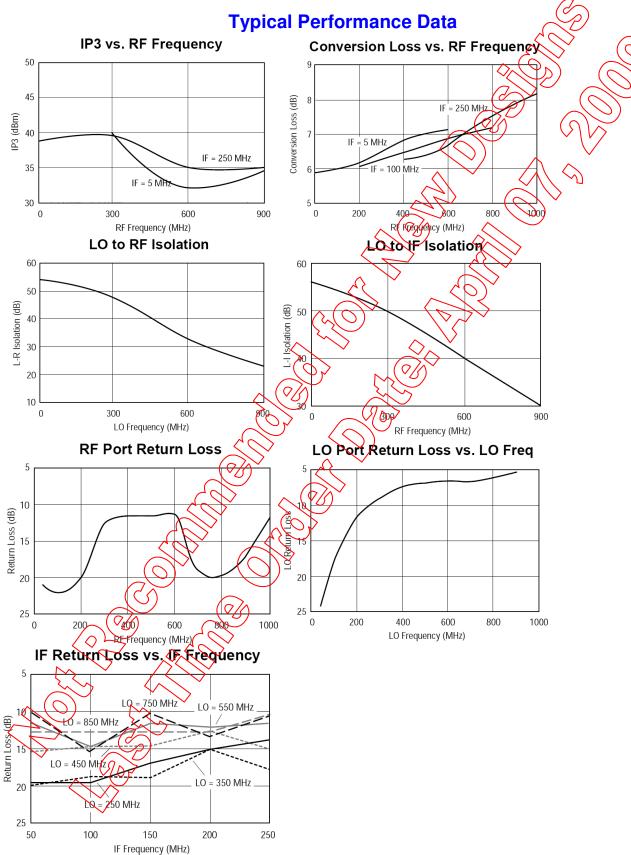
Operation of this device above any of these parameters may cause permanent damage. Total sum of LO port and RF port power should not exceed 25 dBm.

Ordering Information

Part No.	Description
HMJ5	High Dynamic Range FET Mixer



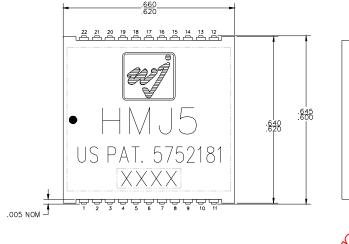


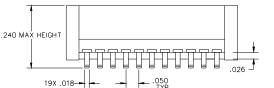










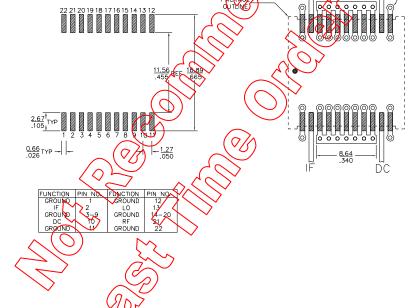


Dimensions are expressed in Inches TOLERANCE (XXX).0) 5 .XX [.02

Drawing is illustrated at Max dimensions.

ø <u>0.51</u> MIN

Land Pattern / Mounting Configuration



Product Marking

The component will be marked with an four-digit "HMJ7" designator with alphanumeric lot number XXXX

Tape and peel specifications for this part are located on the website in the "Application Notes section.

ESD Information

Caution ESD sensitive device.

ESD Rating: Class 2

Passes at 2000 V Value:

Human Body Model (HBM) Test. JEDEC Standard JESD22-A114 Standard.

ESI) Rating: Value:

Class IV Passes at 2000 V

Test:

Charged Device Model (CDM) Standard: JEDEC Standard JESD22-C101

Mounting Config. Notes

- 1. Ground vias are critical for thermal and RF grounding considerations.
- A minimum of 36 ground vias are required for 14 mil FR4 boards.
- If your PCB design rules allow, ground vias should be placed under the land pattern for better RF and thermal performance. Otherwise ground vias should be placed as close to the land pattern as possible.
- 4. Trace width depends on the PCB material.